

AN6295NK

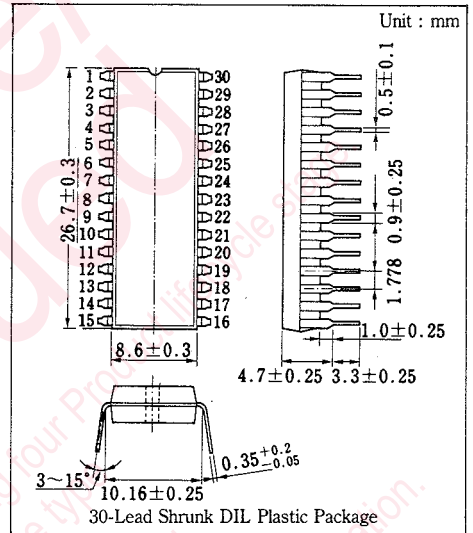
Dual Hi-Fi VTR Peak-Noise-Reduction Circuit

■ Outline

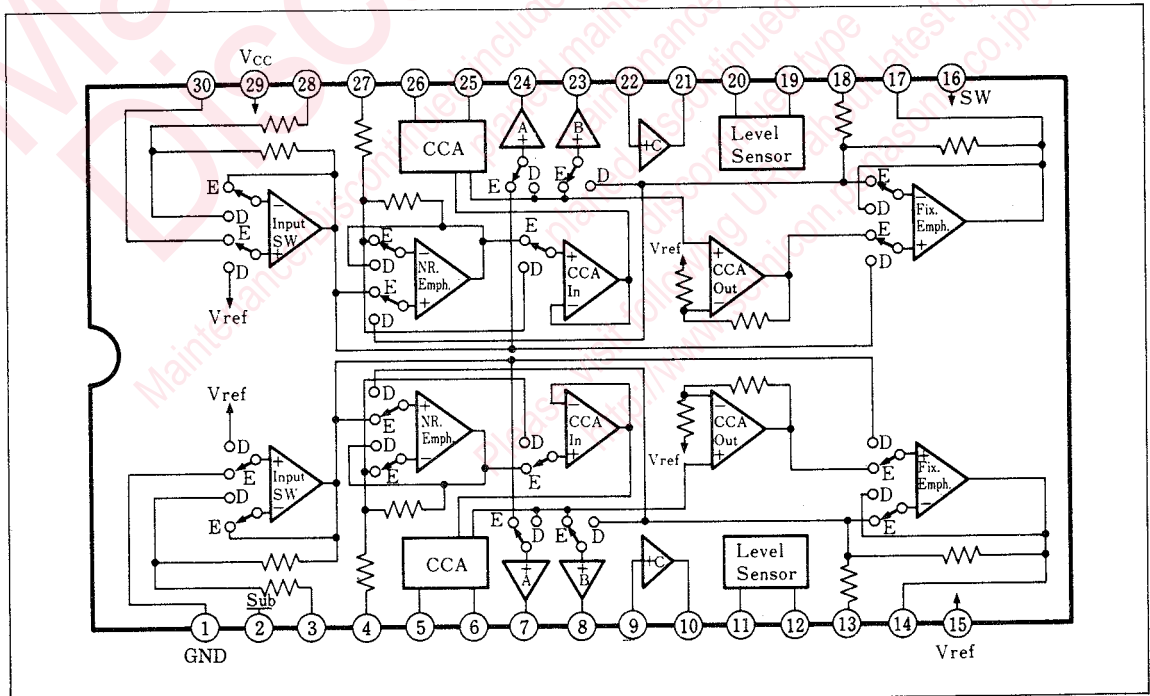
The AN6295NK is an integrated circuit designed for the Hi-Fi VTR noise reduction and responds to the stereo operation with one chip. Its dynamic range is 110dB and its S/N ratio is 80dB or over. It has fewer external parts because it is equipped with a built-in resistance for time constants.

■ Features

- All circuit blocks are included.
- Minimum number of external components
- Wide dynamic range: 110dB



■ Block Diagram



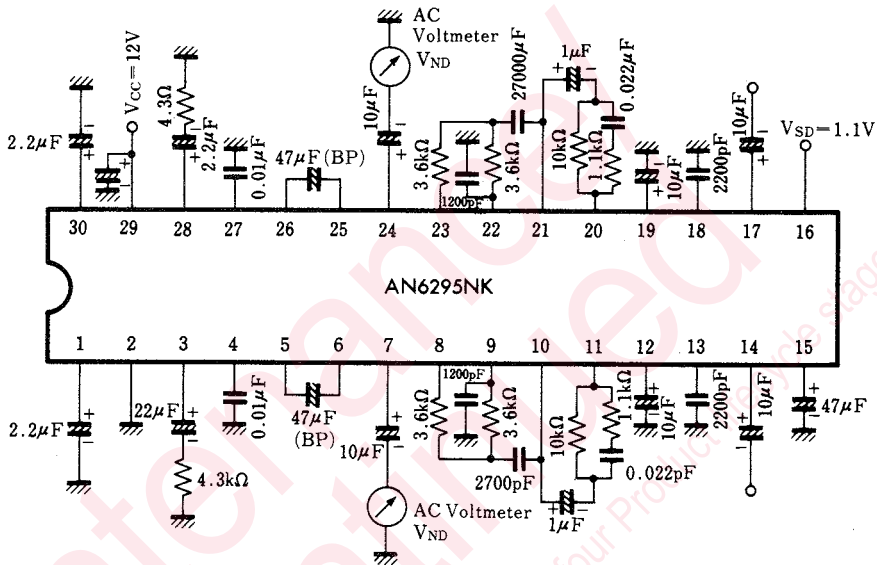
■ Absolute Maximum Ratings (Ta=25°C)

| Item | Symbol | Rating | Unit |
|-------------------------------|------------------|----------|------|
| Supply Voltage | V _{CC} | 14.4 | V |
| Supply Current | I _{CC} | 40 | mA |
| Power Dissipation | P _D | 560 | mW |
| Operating Ambient Temperature | T _{opr} | -20~+75 | °C |
| Storage Temperature | T _{stg} | -55~+125 | °C |

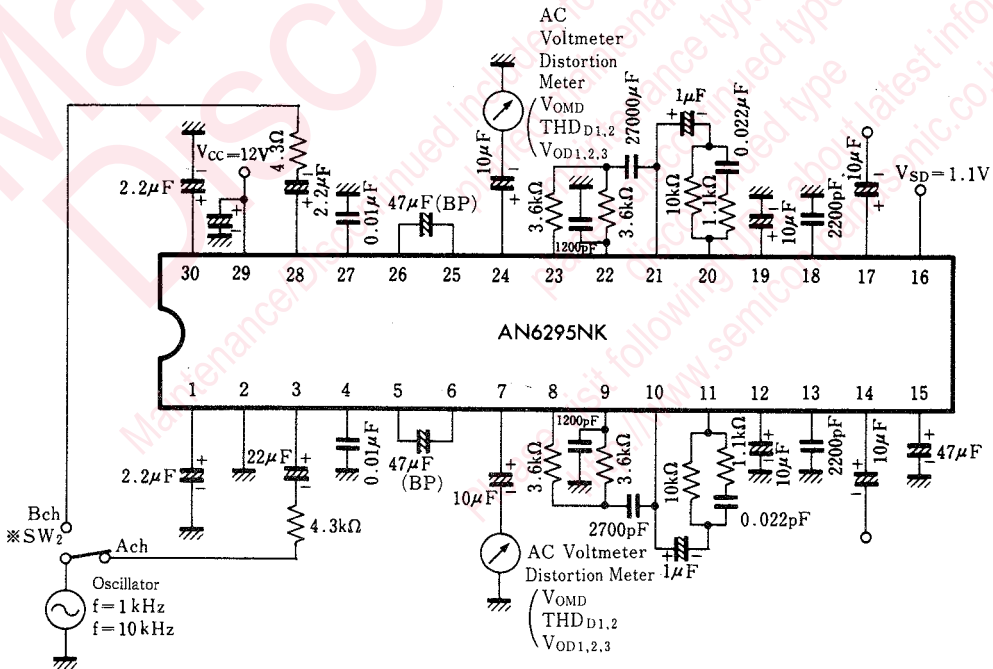
■ Electrical Characteristics (V_{CC}=12V, Ta=25°C)

| Item | Symbol | Test Circuit | Condition | min. | typ. | max. | Unit |
|-------------------------------------|--------------------------|--------------|--|-------|------|-------|------|
| Supply Current | I _{CQ} | 1 | Encode, Input: GND | | 17 | 23 | mA |
| Encode Holding Voltage | V _{SE} | | | 3.7 | | | V |
| Decode Holding Voltage | V _{SD} | | | | | 1.1 | V |
| Encode Maximum Output Voltage | V _{OME} | 2 | f=1kHz, THD=3% | 0 | 2 | | dBV |
| Decode Maximum Output Voltage | V _{OMD} | 4 | f=1kHz, THD=3% | 0 | 5 | | dBV |
| Encode Harmonic Distortion-1 | THD _{E1} | 2 | V _{IN} =1kHz, -22dBV | | 0.25 | 0.4 | % |
| Encode Harmonic Distortion-2 | THD _{E2} | 2 | V _{IN} =10kHz, -22dBV | | 0.8 | 1 | % |
| Decode Harmonic Distortion-1 | THD _{D1} | 4 | V _{IN} =1kHz, -15dBV | | 0.15 | 0.3 | % |
| Decode Harmonic Distortion-2 | THD _{D2} | 4 | V _{IN} =1kHz, -10.5dBV | | 0.6 | 1 | % |
| Encode Noise Output Voltage | V _{NE} | 1 | Input: GND, DIN AUDIO | | -54 | -50 | dBV |
| Decode Noise Output Voltage | V _{ND} | 3 | Input: GND, DIN AUDIO | | -104 | -100 | dBV |
| Encode Output Voltage-1 | V _{OE1} | 2 | V _{IN} =1kHz, -22dBV | -14 | -12 | -10 | dBV |
| Encode Output Voltage-2 | V _{OE2} | 2 | V _{IN} =1kHz, -62dBV | -36 | -33 | -30 | dBV |
| Encode Output Voltage-3 | V _{OE3} | 2 | V _{IN} =1kHz, -82dBV | -47 | -43 | -41 | dBV |
| Decode Output Voltage-1 | V _{OD1} | 4 | V _{IN} =1kHz, -15dBV | -24 | -22 | -20 | dBV |
| Decode Output Voltage-2 | V _{OD2} | 4 | V _{IN} =1kHz, -35dBV | -63 | -62 | -57 | dBV |
| Decode Output Voltage-3 | V _{OD3} | 4 | V _{IN} =1kHz, -54dBV | -84 | -82 | -76 | dBV |
| Encode Monitor Output Voltage | V _{OM} | 2 | V _{IN} =1kHz, -22dBV | -23.5 | -22 | -20.5 | dBV |
| Encode Monitor Output Distortion | THD _M | 2 | V _{IN} =1kHz, -22dBV | | 0.03 | 0.1 | % |
| Encode Monitor Output Noise Voltage | V _{NM} | 2 | Input: GND, DIN AUDIO | | -104 | -100 | dBV |
| Encode Crosstalk | CT _E | 5 | V _{IN} =1kHz, -5dBV to Encode Input | | -49 | -46 | dBV |
| Decode Crosstalk | CT _D | 6 | V _{IN} =1kHz, -15dBV | | -75 | -70 | dBV |
| Encode Channel Balance | CB _E | 2 | V _{IN} =1kHz, -22dBV | -1.5 | 0 | 1.5 | dB |
| Decode Channel Balance | CB _D | 4 | V _{IN} =1kHz, -15dBV | -2 | 0 | 2 | dB |
| Encode Channel Separation | SEP _E | 7 | V _{IN} =1kHz, -22dBV | | -53 | -48 | dBV |
| Decode Channel Separation | SEP _D | 8 | V _{IN} =1kHz, -15dBV | | -95 | -85 | dBV |
| Operating Supply Voltage | V _{opr} | | | 11.5 | 12 | 12.5 | V |
| Encode Input Impedance | Z _{INE} | 9 | f=1kHz | | 30 | | kΩ |
| Decode Input Impedance | Z _{IND} | 10 | f=1kHz | | 5 | | kΩ |
| Encode Frequency Characteristic | V _{OE} (10k/1k) | 11 | V _N =-20dBV, f=Ratio of 1kHz to 10kHz | 3.2 | 4.2 | 5.2 | dB |
| Decode Frequency Characteristic | V _{OD} (10k/1k) | 12 | V _N =-15dBV, f=Ratio of 1kHz to 10kHz | -10.7 | -8.7 | -6.7 | dB |

Test Circuit 3 (V_{ND})

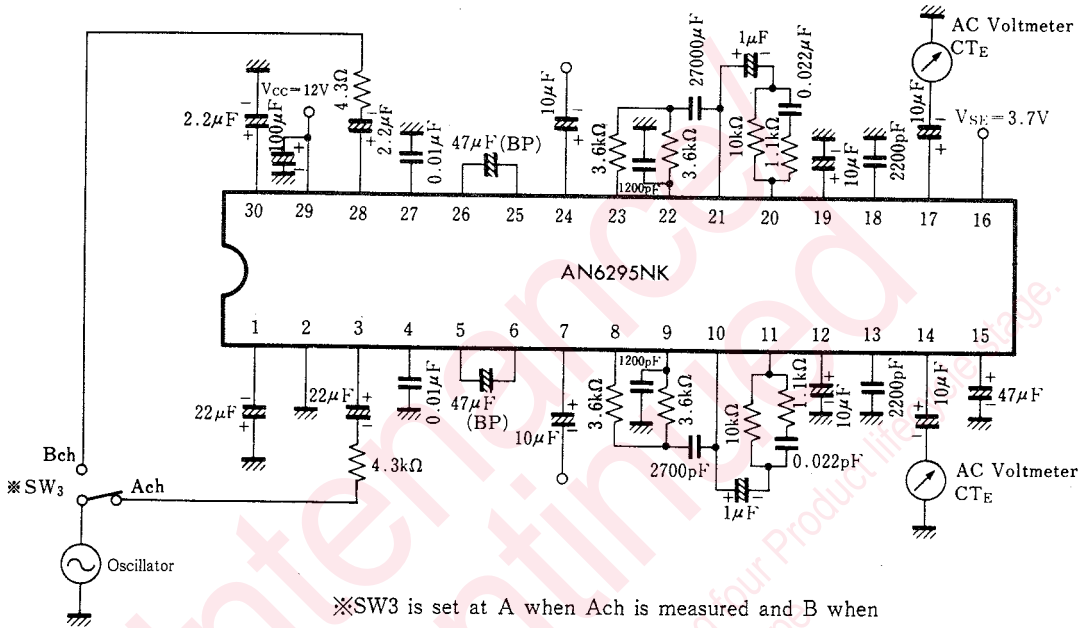


Test Circuit 4 (V_{OMD} , THD_1 , THD_2 , V_{OD1} , V_{OD2} , V_{OD3} , CB_D)



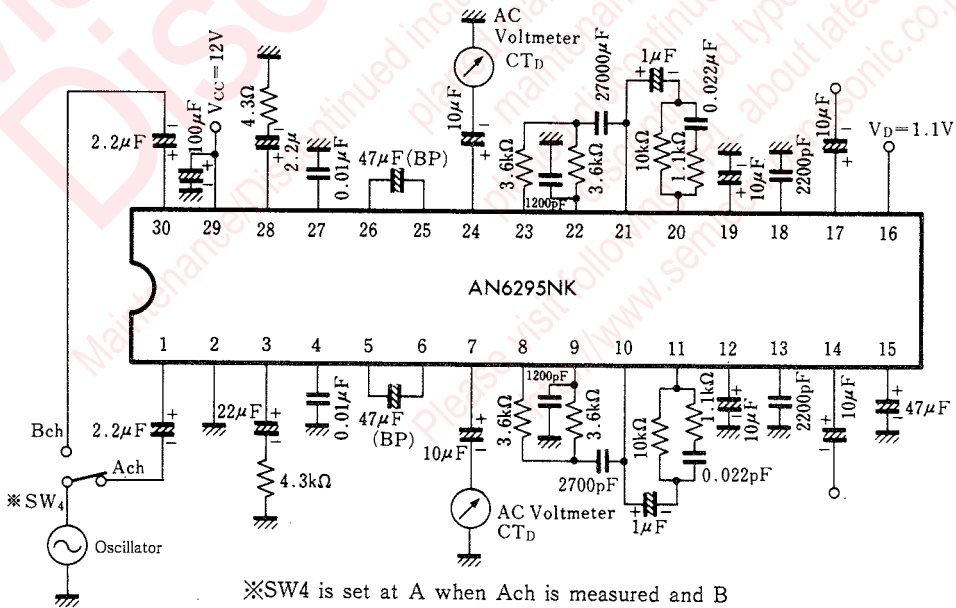
※ SW_2 is set at A when Ach is measured and B when Bch is measured.

Test Circuit 5(CT_E)



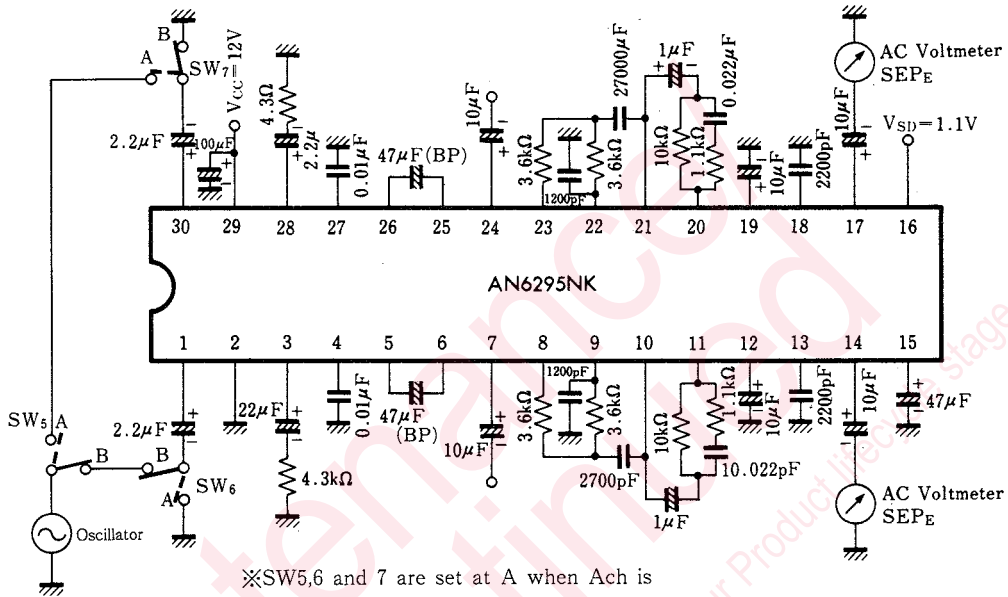
※SW₃ is set at A when A_{ch} is measured and B when B_{ch} is measured.

Test Circuit 6(CT_D)



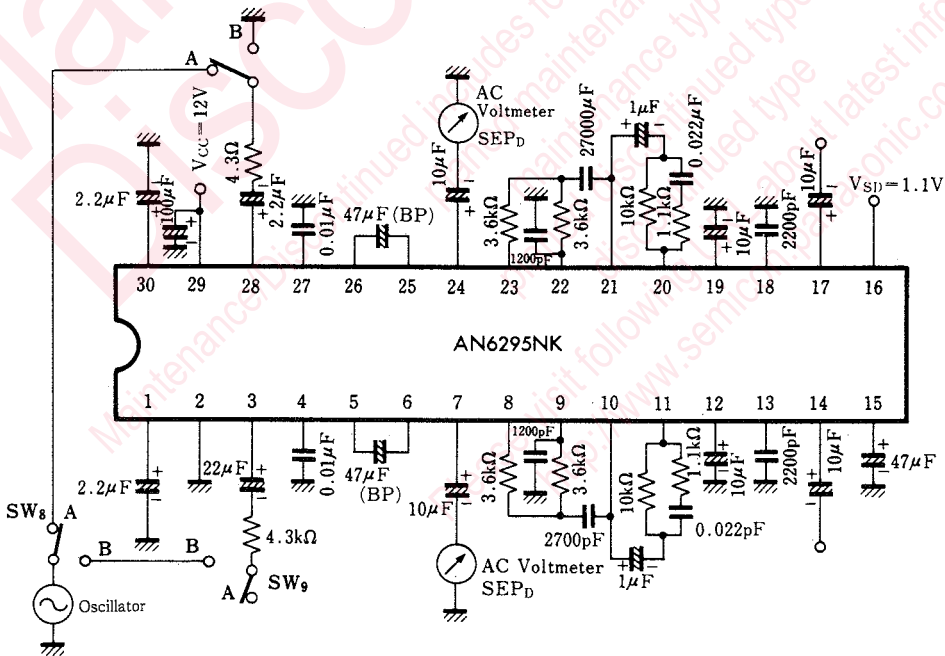
※SW₄ is set at A when A_{ch} is measured and B when B_{ch} is measured.

Test Circuit 7 (SEP_E)



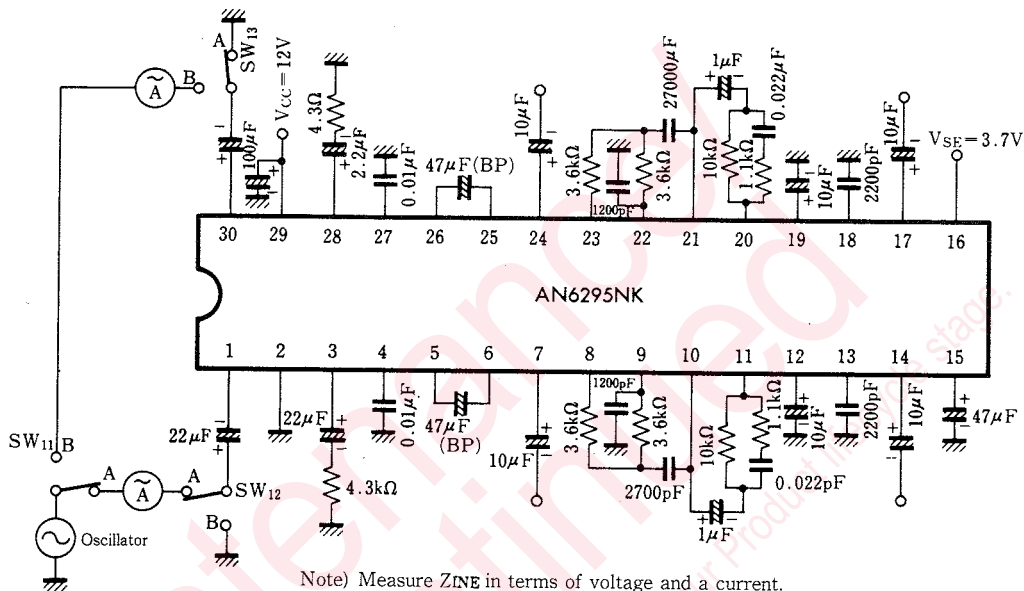
※SW_{5,6} and 7 are set at A when Ach is measured and B when Bch is measured.

Test Circuit 8 (SEP_D)



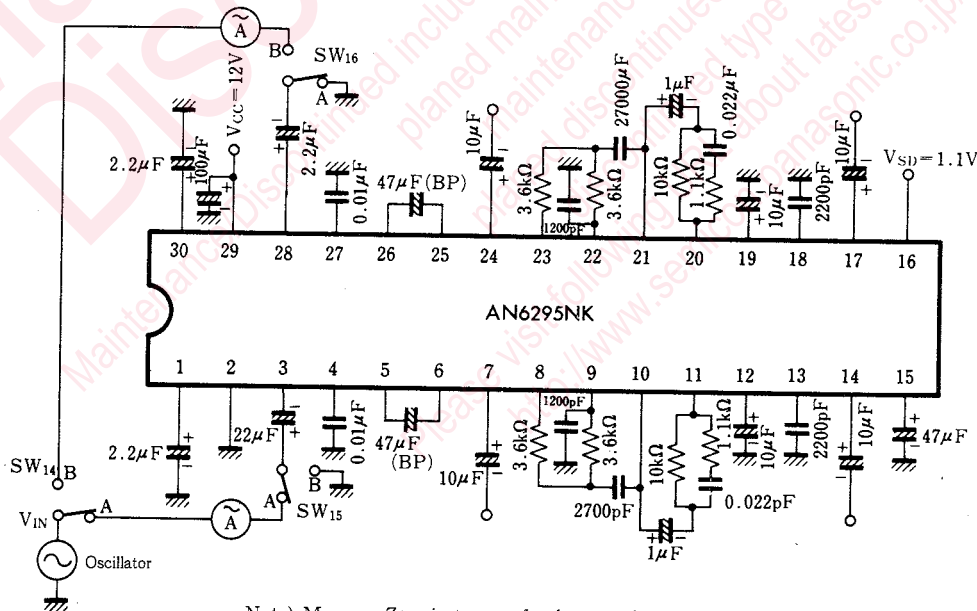
※SW_{8,9} and 10 are set at A when Ach is measured and B when Bch is measured.

Test Circuit 9 (Z_{INE})



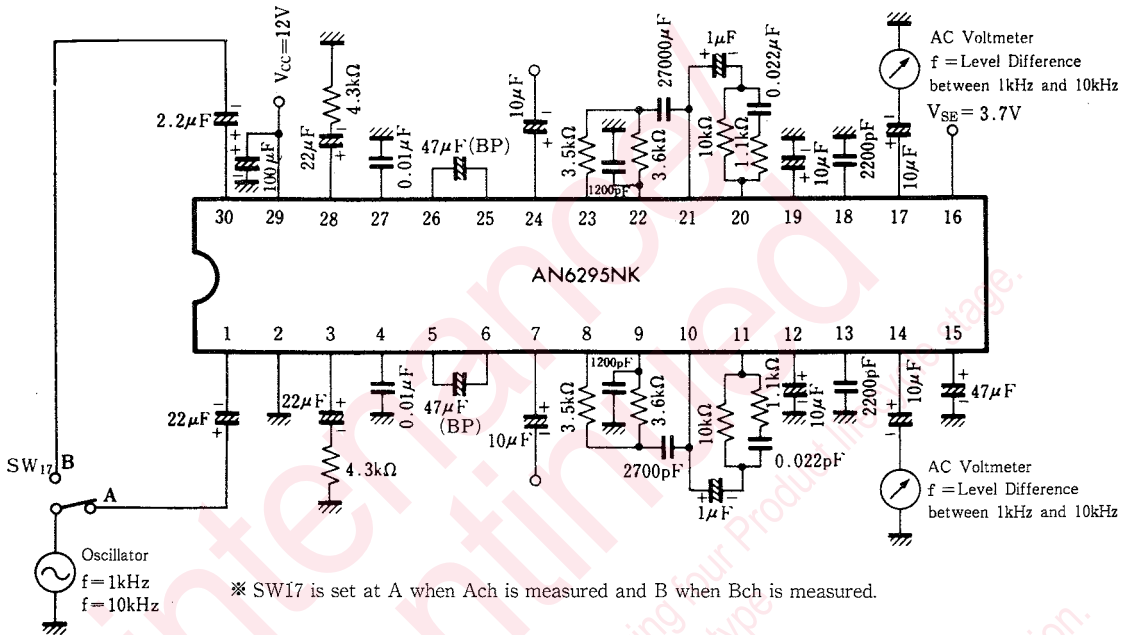
Note) Measure Z_{INE} in terms of voltage and a current.
 SW11, 12, and 13 are set at A when A_{ch} is measured and B when B_{ch} is measured.

Test Circuit 10 (Z_{IND})

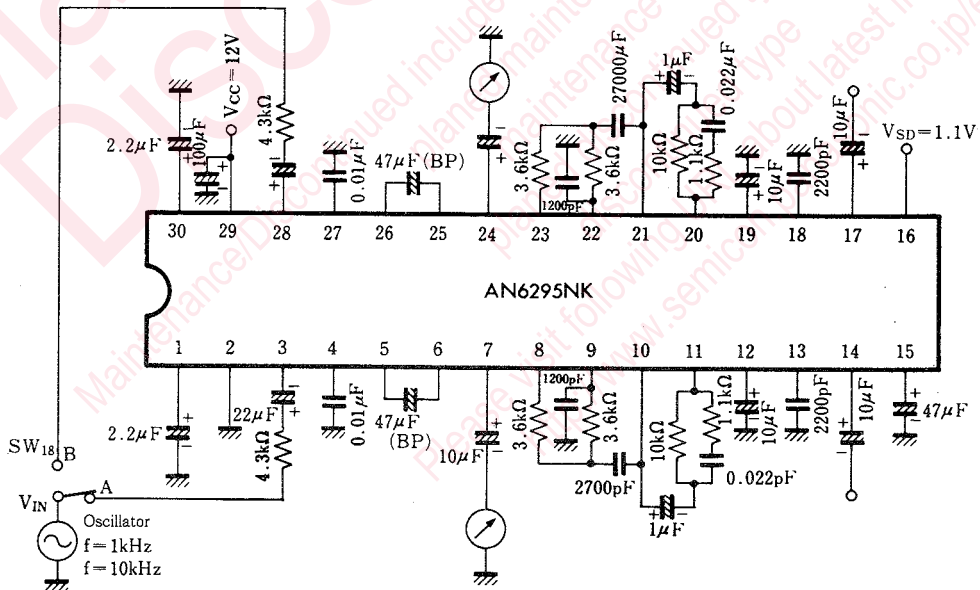


Note) Measure Z_{IND} in terms of voltage and a current. SW14, 15 and 16 are set at A when A_{ch} is measured and B when B_{ch} is measured.

Test Circuit 11 (V_{OE} (10k/1k))



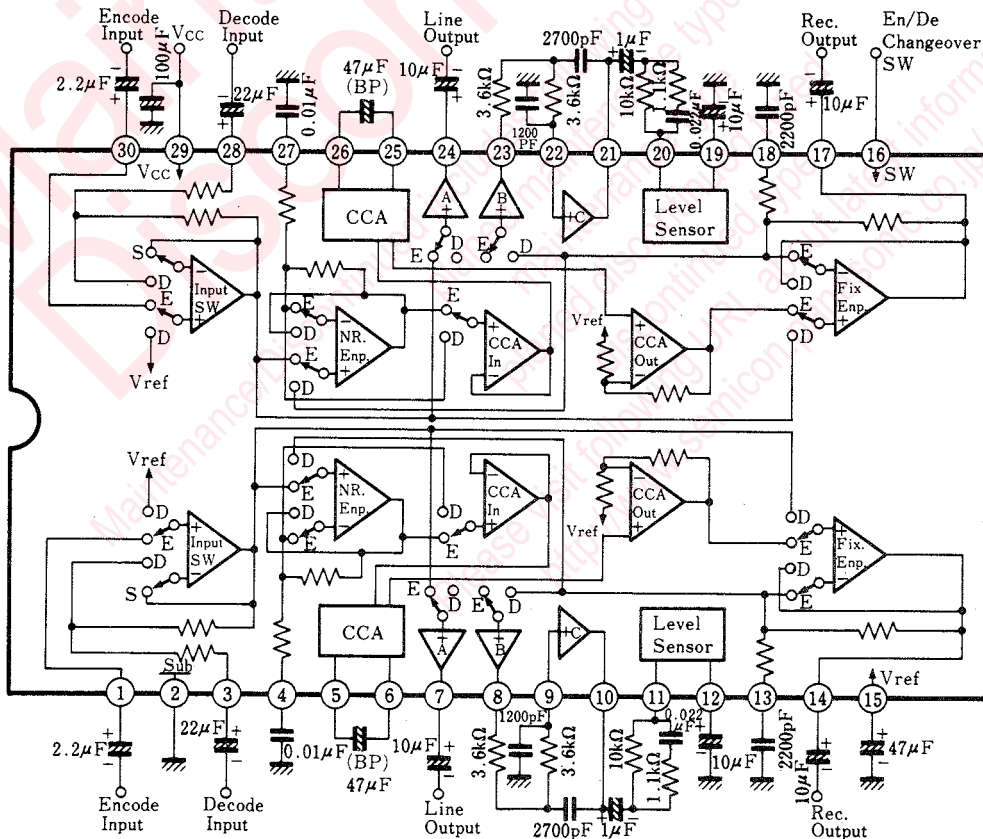
Test Circuit 12 (V_{OD} (10k/1k))



■ Pin

| Pin No. | Pin Name | Pin No. | Pin Name |
|---------|----------------------------|---------|----------------------------|
| 1 | Encode Input (Ach) | 16 | En/D. Changeover SW |
| 2 | GND | 17 | Rec Output (Bch) |
| 3 | Decode Input (Ach) | 18 | Output Emphasis (Bch) |
| 4 | NR Emphasis (Ach) | 19 | Timing Capacitor (Bch) |
| 5 | CCA Gain Cell Output (Ach) | 20 | Level Sensor Input (Bch) |
| 6 | CCA Amp. Input (Ach) | 21 | Filter Amp. Output (Bch) |
| 7 | Line Output (Ach) | 22 | Filter Amp. Input (Bch) |
| 8 | Buffer Amp. Output (Ach) | 23 | Filter Amp. Output (Bch) |
| 9 | Filter Amp. Input (Ach) | 24 | Line Output (Bch) |
| 10 | Filter Amp. Output (Ach) | 25 | CCA Amp. Input (Bch) |
| 11 | Level Sensor Input (Ach) | 26 | CCA Gain Cell Output (Bch) |
| 12 | Timing Emphasis (Ach) | 27 | NR Emphasis (Bch) |
| 13 | Output Emphasis (Ach) | 28 | Decode Input (Bch) |
| 14 | Rec Output (Ach) | 29 | V _{cc} |
| 15 | Reference Voltage | 30 | Encode Input (Bch) |

■ Application Circuit



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